Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Glass	
Overall Length:	
0.260 inches	
Overall Diameter:	
0.060 inches	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Germanium	
Voltage Rating In Volts Per Characteristic:	
15.0 reverse voltage, peak	
Current Rating Per Characteristic:	
0.10 amperes forward current, average	
Power Rating Per Characteristic:	
80.0 watts small-signal input power, common-collector preset	
Maximum Operating Tempurature Per Measurement Point:	
85.0 degrees celsius junction	
Precious Material And Location:	
External surfaces gold	
Precious Material:	
Gold	
Terminal Type And Quantity:	
2 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	